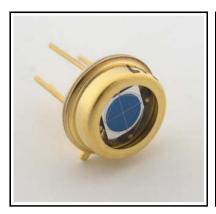
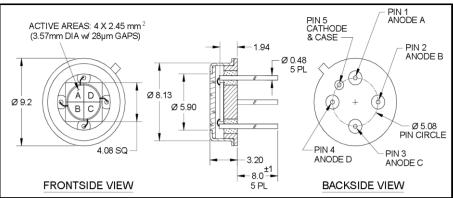


Version 24-11-11







#### **Features**

- 10 mm² Quadrant PIN detector
- High sensitivity
- Small gap
- Low dark current

# Description

Low dark current circular active area quadrant PIN photodiode with 4 x  $2.45 \text{ mm}^2$  active area. Metal can type hermetic TO5 package with clear glass window.

# **Application**

- Laser beam position sensor
- Autocollimators
- Optical tweezers
- Ellipsometers

### **RoHS**

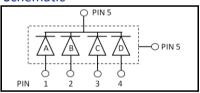
2002/95/EC



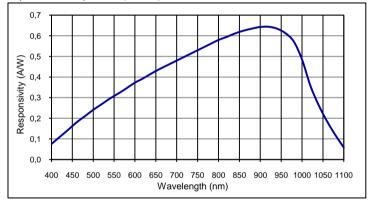
#### Absolute maximum ratings

<u> </u>							
Symbol	Parameter	Min	Max	Unit			
$T_{STG}$	Storage temp	-55	125	°C			
T <sub>OP</sub>	Operating temp	-40	100	°C			
$V_{max}$	Max reverse voltage		20	٧			
IDEAL	Peak DC current		10	mA			

## Schematic



## Spectral response (23 °C)



## Electro-optical characteristics @ 23 °C

Symbol	Characteristic	Test Condition	Min	Тур	Max	Unit
	Number of elements			4 quadrants		
	Active area		diam	diameter 3570 (total)		μm
	Active area	per element		2.45		mm²
	Gap	between elements		28		μm
I <sub>D</sub>	Dark current	V <sub>R</sub> = 10 V; per element		0.4		nA
С	Capacitance	$V_R = 0 V$ ; per element		30		pF
		V <sub>R</sub> = 10 V; per element		5		pF
	Responsivity	λ = 632 nm		0.4		A/W
		λ = 900 nm		0.64		A/W
t <sub>R</sub>	Rise time	$V_R = 0 \text{ V}; \lambda = 850 \text{ nm}; R_L = 50 \Omega$		2000		ns
		$V_R = 10 \text{ V}; \lambda = 850 \text{ nm}; R_L = 50 \Omega$		20		ns
		$V_R = 80 \text{ V}; \lambda = 850 \text{ nm}; R_L = 50 \Omega$		10		ns
	Shunt Resistance	$V_R = 5$ mV; per element		250		МΩ
	N.E.P.	$V_R = 5 \text{ V}; \lambda = 900 \text{ nm}; \text{ per element}$		1.8 E-14		W/√Hz
$V_{BR}$	Breakdown voltage	Ι <sub>P</sub> = 2 μΑ	20	50		V

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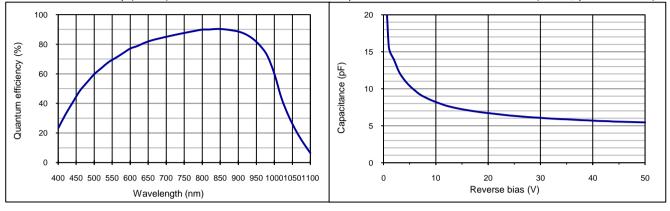




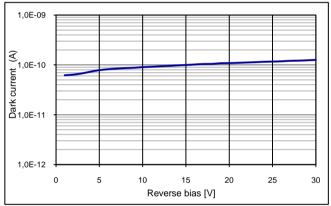
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## Quantum efficiency (23 °C)

## Capacitance as fct of reverse bias (23 °C; per element)



## Dark current as fct of bias (23 °C; per element)



#### Package dimension:

Small quantities: Foam pad, boxed (12 cm x 16.5 cm)

#### Handling precautions:

- $\bullet$  Soldering temperature max. 260 °C for 10 s. The device must be protected against solder flux vapour.
- Minimum pin length is 2 mm.
- For ESD protection standard precautionary measures are sufficient.
- For further questions please refer to document "Instructions for handling and processing".

Disclaimer: Due to our strive for continuous improvement, specifications are subject to change within our PCN policy according to JESD46C.



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QP10-6-T05